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April 2001

FDC602P

P-Channel 2.5V PowerTrench[®] Specified MOSFET

General Description

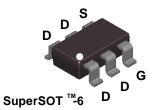
This P-Channel 2.5V specified MOSFET uses a rugged gate version of Fairchild's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

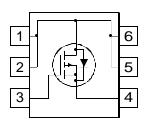
Applications

- Battery management
- Load switch
- Battery protection

Features

- -5.5 A, -20 V $R_{DS(ON)} = 35 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 50 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
- Fast switching speed
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-20	V	
V _{GSS}	Gate-Source Voltage		±12	V	
D	Drain Current – Continuous	(Note 1a)	-5.5	A	
	– Pulsed		-20		
Po	Maximum Power Dissipation	(Note 1a)	1.6	W	
		(Note 1b)	0.8		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	

Thermal Characteristics

R _{0JA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _{0JC}	Thermal Resistance, Junction-to-Case	(Note 1)	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.602	FDC602P	7"	8mm	3000 units

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FDC602P

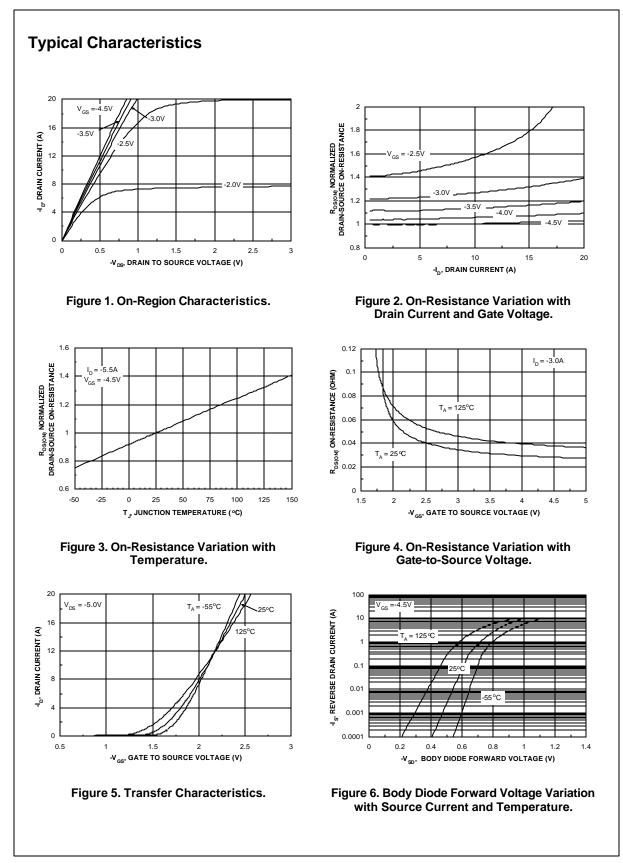
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	I				
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-14		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$, $V_{GS} = 0 V$			-1	μA
GSSF	Gate–Body Leakage, Forward	$V_{GS} = 12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = -12 V$, $V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.6	-0.9	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \ V, I_D = -5.5 \ A \\ V_{GS} = -2.5 \ V, I_D = -4.5 \ A \\ V_{GS} = -4.5 \ V, I_D = -5.5 \ A \\ T_{J} = 125^{\circ} C \end{array} $		27 38 38	35 50 53	mΩ
D(on)	On-State Drain Current	$V_{GS} = -4.5 V$, $V_{DS} = -5 V$	-20			Α
g FS	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -5.5 A$		19		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		1456		pF
Coss	Output Capacitance	f = 1.0 MHz		300		pF
Crss	Reverse Transfer Capacitance			150		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -10 V$, $I_D = -1 A$,		15	27	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$		11	20	ns
t _{d(off)}	Turn–Off Delay Time			57	91	ns
t _f	Turn–Off Fall Time			37	59	ns
Qg	Total Gate Charge	$V_{DS} = -10 V$, $I_D = -5.5 A$,		14	20	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		3		nC
Q _{gd}	Gate-Drain Charge	1		5		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source				-1.3	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -1.3 A$ (Note 2)		-0.7	-1.2	V

 R_{0.0} is the sum of the junction-to-case and case-to-ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0.0} is guaranteed by design while R_{0.0} is determined by the user's board design.

a. 78°C/W when mounted on a 1in² pad of 2oz copper on FR-4 board.

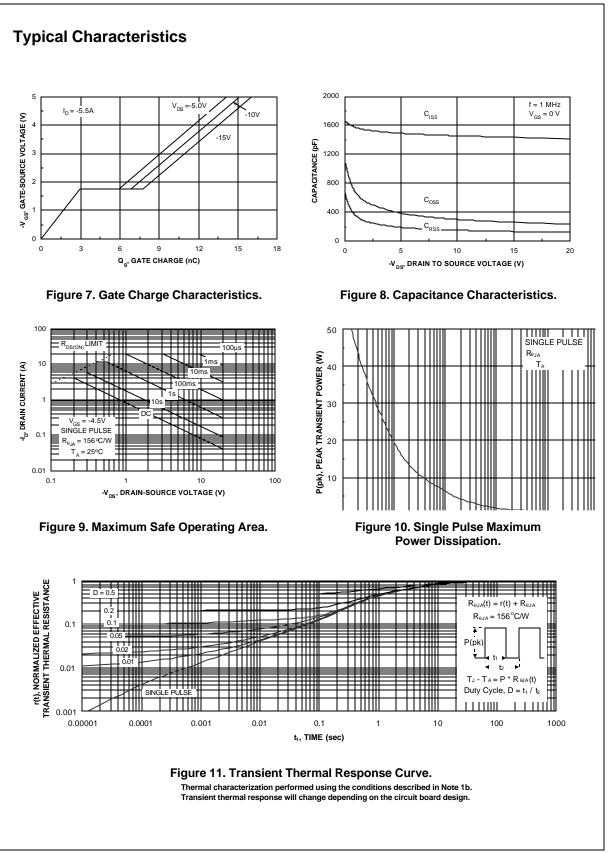
b. 156°C/W when mounted on a minimum pad.

2. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%



FDC602P

FDC602P Rev C(W)



FDC602P

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